



**TGBR10V200**

Advance

**DIODE**

**TRENCH MOS SCHOTTKY BARRIER RECTIFIER**

■ DESCRIPTION

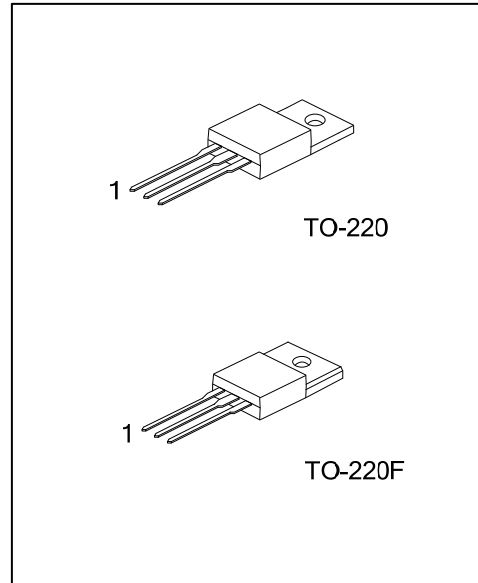
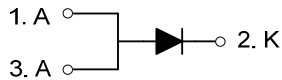
The UTC **TGBR10V200** is a trench mos schottky barrier rectifier, it uses UTC's advanced technology to provide customers with low forward voltage drop and high current capability, etc.

The UTC **TGBR10V200** suitable for free wheeling, high frequency inverters, polarity protection, and low voltage.

■ FEATURES

- \* Very low forward voltage drop
- \* High current capability
- \* High surge capability
- \* High efficiency

■ SYMBOL



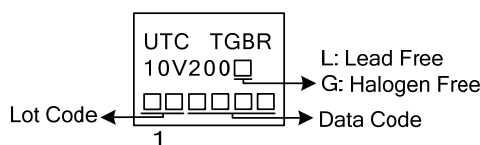
■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
TGBR10V200L-TA3-T	TGBR10V200G-TA3-T	TO-220	A	K	A	Tube
TGBR10V200L-TF3-T	TGBR10V200G-TF3-T	TO-220F	A	K	A	Tube

Note: Pin Assignment: A: Anode K: Cathode

<p>TGBR10V200L-TA3-T</p> <p>(1) Packing Type</p> <p>(2) Package Type</p> <p>(3) Green Package</p>	<p>(1) T: Tube</p> <p>(2) TA3: TO-220, TF3: TO-220F</p> <p>(3) L: Lead Free, G: Halogen Free and Lead Free</p>
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■ MARKING



■ ABSOLUTE MAXIMUM RATINGS ( $T_A=25^{\circ}\text{C}$  unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER	SYMBOL	RATINGS	UNIT
DC Blocking Voltage (Note 1)	$V_{RM}$	200	V
Working Peak Reverse Voltage	$V_{RWM}$	200	V
Peak Repetitive Reverse Voltage	$V_{RRM}$	200	V
Average Rectified Output Current	$I_O$	10	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	$I_{FSM}$	180	A
Operating Junction Temperature	$T_J$	-65~+150	$^{\circ}\text{C}$
Storage Temperature	$T_{STG}$	-65~+150	$^{\circ}\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL CHARACTERISTICS (PER LEG)

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	$\theta_{JA}$	62.5	$^{\circ}\text{C}/\text{W}$
Junction to Case	TO-220	2	$^{\circ}\text{C}/\text{W}$
	TO-220F	3.31	

■ ELECTRICAL CHARACTERISTICS ( $T_A=25^{\circ}\text{C}$  unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	$I_R=0.50\text{mA}$	200			V
Forward Voltage Drop	$V_{FM}$	$I_F=10\text{A}, T_C=25^{\circ}\text{C}$			0.90	V
		$I_F=10\text{A}, T_C=125^{\circ}\text{C}$			0.80	V
Peak Reverse Current at Rated DC Blocking Voltage (Note 1)	$I_{RM}$	$V_R=200\text{V}, T_C=25^{\circ}\text{C}$			100	$\mu\text{A}$
		$V_R=200\text{V}, T_C=125^{\circ}\text{C}$			10	$\text{mA}$

Notes: 1. Short duration pulse test used to minimize self-heating effect.

2. Thermal resistance junction to case mounted on heatsink.

3. Mounted on an FR4 PCB, single-sided copper, with  $100\text{cm}^2$  copper pad area.

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